

# 2SD225900A Datasheet

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DiGi Electronics Part Number 2SD225900A-DG

Manufacturer Panasonic Electronic Components

Manufacturer Product Number 2SD225900A

Description TRANS NPN 20V 0.7A MT-2

**Detailed Description** Bipolar (BJT) Transistor NPN 20 V 700 mA 55MHz 1 W

Through Hole MT-2-A1



Tel: +00 852-30501935

RFQ Email: Info@DiGi-Electronics.com

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## **Purchase and inquiry**

Manufacturer Product Number:	Manufacturer:			
2SD225900A	Panasonic Electronic Components			
Series:	Product Status:			
	Obsolete			
Transistor Type:	Current - Collector (Ic) (Max):			
NPN	700 mA			
Voltage - Collector Emitter Breakdown (Max):	Vce Saturation (Max) @ lb, lc:			
20 V	400mV @ 50mA, 500mA			
Current - Collector Cutoff (Max):	DC Current Gain (hFE) (Min) @ Ic, Vce:			
10μΑ	1000 @ 150mA, 10V			
Power - Max:	Frequency - Transition:			
1 W	55MHz			
Operating Temperature:	Mounting Type:			
150°C (TJ)	Through Hole			
Package / Case:	Supplier Device Package:			
3-SIP	MT-2-A1			
Base Product Number:				
2SD2250				

## **Environmental & Export classification**

Moisture Sensitivity Level (MSL):	ECCN:
1 (Unlimited)	EAR99
HTSUS:	
8541.29.0075	

## 2SD2259

### Silicon NPN epitaxial planar type

For low-frequency amplification

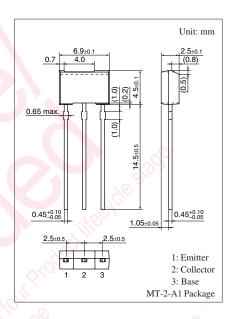
#### ■ Features

- High forward current transfer ratio h<sub>FE</sub>
- ullet Low collector-emitter saturation voltage  $V_{\text{CE(sat)}}$
- Allowing supply with the radial taping

#### ■ Absolute Maximum Ratings $T_a = 25$ °C

Parameter	Symbol	Rating	Unit	
Collector-base voltage (Emitter open)	$V_{CBO}$	20	V	
Collector-emitter voltage (Base open)	$V_{CEO}$	20	V	
Emitter-base voltage (Collector open)	V <sub>EBO</sub>	15	V	
Collector current	$I_{C}$	0.7	A	
Peak collector current	$I_{CP}$	1.5	A	
Collector power dissipation *	P <sub>C</sub>	1	W	
Junction temperature	T <sub>j</sub>	150	°C	
Storage temperature	T <sub>stg</sub>	-55 to +150	°CO	

Note) \*: Printed circuit board: Copper foil area of 1 cm<sup>2</sup> or more, and the board thickness of 1.7 mm for the collector portion



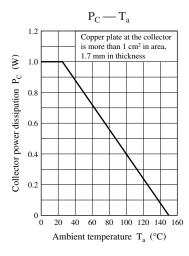
#### ■ Electrical Characteristics $T_a = 25$ °C $\pm 3$ °C

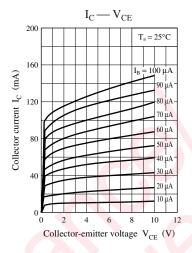
Parameter	Symbol	Conditions	Min	Тур	Max	Unit
Collector-base voltage (Emitter open)	$V_{CBO}$	$I_C = 10 \mu\text{A}, I_E = 0$	20	0.0		V
Collector-emitter voltage (Base open)	$V_{CEO}$	$I_C = 1 \text{ mA}, I_B = 0$	20			V
Emitter-base voltage (Collector open)	$V_{EBO}$	$I_E = 10 \mu\text{A}, I_C = 0$	15			V
Collector-base cutoff current (Emitter open)	$I_{CBO}$	$V_{CB} = 15 \text{ V}, I_{E} = 0$			1	μΑ
Collector-emitter cutoff current (Base open)	$I_{CEO}$	$V_{CE} = 15 \text{ V}, I_{B} = 0$			10	μΑ
Forward current transfer ratio *	h <sub>FE</sub>	$V_{CE} = 10 \text{ V}, I_{C} = 150 \text{ mA}$	1 000		2500	_
Collector-emitter saturation voltage *	V <sub>CE(sat)</sub>	$I_C = 500 \text{ mA}, I_B = 50 \text{ mA}$		0.15	0.40	V
Transition frequency	$f_T$	$V_{CB} = 20 \text{ V}, I_E = -20 \text{ mA}, f = 200 \text{ MHz}$		55		MHz
Collector output capacitance	C <sub>ob</sub>	$V_{CB} = 10 \text{ V}, I_E = 0, f = 1 \text{ MHz}$		10	15	pF
(Common base, input open circuited)						

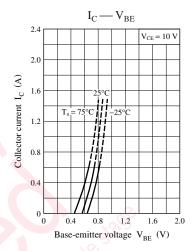
Note) 1. Measuring methods are based on JAPANESE INDUSTRIAL STANDARD JIS C 7030 measuring methods for transistors.

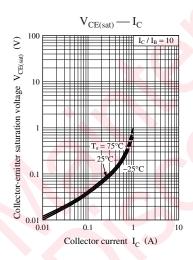
2. \*: Pulse measurement

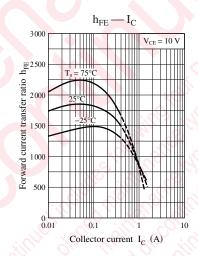
### **Panasonic**

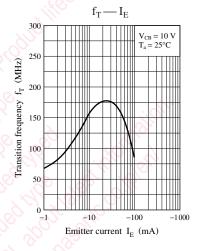


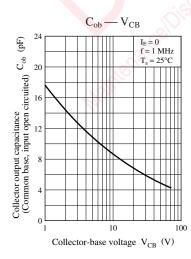












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Tel: +00 852-30501935

RFQ Email: Info@DiGi-Electronics.com